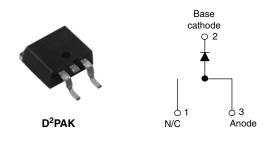
RoHS

COMPLIANT

Vishay High Power Products

Schottky Rectifier, 15 A



SHA

PRODUCT SUMMARY					
I _{F(AV)} 15 A					
V _R	35 to 45 V				

FEATURES

- 150 °C T_J operation
- Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for Q101 level

DESCRIPTION

The 12TQ...SPbF Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	15	A				
V _{RRM}	Range	35 to 45	V				
I _{FSM}	t _p = 5 μs sine	990	A				
V _F	15 Apk, T _J = 125 °C	0.50	V				
TJ	Range	- 55 to 150	۵°				

VOLTAGE RATINGS							
PARAMETER	SYMBOL	12TQ035SPbF	12TQ040SPbF	12TQ045SPbF	UNITS		
Maximum DC reverse voltage	V _R	35	40	45	V		
Maximum working peak reverse voltage	V _{RWM}	35	40	40	v		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS			
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_C = 120 °C, rectangular waveform		15	А		
Maximum peak one cycle non-repetitive surge current I _{FSM} - See fig. 7		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	990	А		
		10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	250			
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 2.4 \text{ A}, L = 5.5 \text{ mH}$		16	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero Frequency limited by TJ maximum	2.4	А			

* Pb containing terminations are not RoHS compliant, exemptions may apply

12TQ....SPbF

Vishay High Power Products Schottky Rectifier, 15 A



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
	V _{FM} ⁽¹⁾	15 A	T ₁ = 25 °C	0.56	V	
Maximum forward voltage drop See fig. 1		30 A	1j=25 C	0.71		
		15 A	T.I = 125 °C	0.50		
		30 A	1J=125 C	0.64		
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	1.75	mA	
See fig. 2	IRM ("	T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	70	IIIA	
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		900	pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body			nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/μ			V/µs	

Note

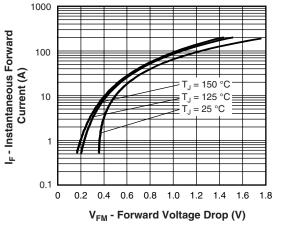
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

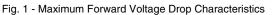
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and sto temperature range	Maximum junction and storage T _J , T _{Stg}			- 55 to 150	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	2.0	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	0/14	
				2	g	
Approximate weight	Approximate weight			0.07	oz.	
Mounting to you o	minimum			6 (5)	kgf ⋅ cm	
Mounting torque	maximum			12 (10)	(lbf · in)	
Marking device			Case style D ² PAK	12TQ	045S	



Schottky Rectifier, 15 A

Vishay High Power Products





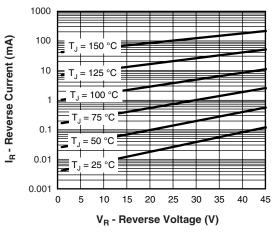


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

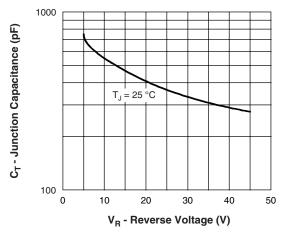


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

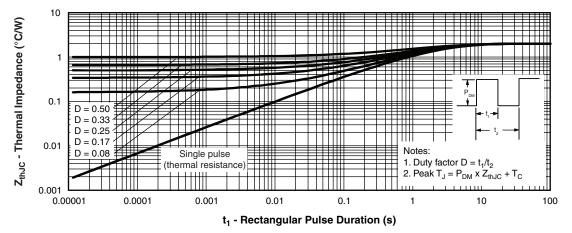
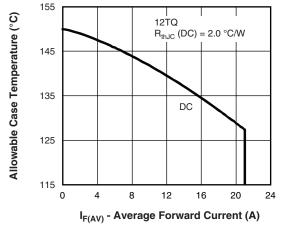
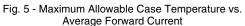


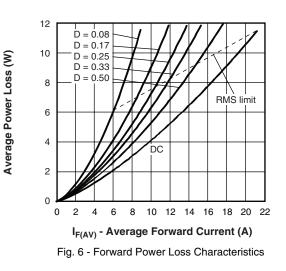
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

12TQ...SPbF

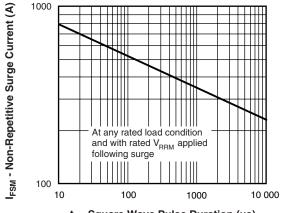
Vishay High Power Products Schottky Rectifier, 15 A







VISHA



 $t_{\rm p}$ - Square Wave Pulse Duration (µs)

Fig. 7 - Maximum Non-Repetitive Surge Current

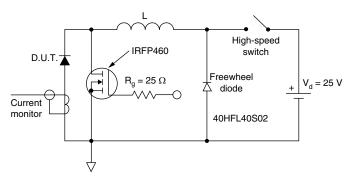


Fig. 8 - Unclamped Inductive Test Circuit



Schottky Rectifier, 15 A

Vishay High Power Products

ORDERING INFORMATION TABLE

Device code	12	т	Q	045	S	TRL	PbF	
		2	3	4	5	6	7	
	1 · 2 ·		rent rati kage:	ng				
	3.	T = TO-220 3 - Schottky "Q" series						
	4		tage rati				035 = 3 040 = 4	10 \
	5 · 6 ·		= D ² PA one = Ti	K ube (50	pieces)		045 = 4	15 \
		• TF	RL = Ta	be and r	eel (left			
	7.			pe and r tandard			ted)	
		• PI	bF = Lea	ad (Pb)-i	free			

LINKS TO RELATED DOCUMENTS					
Dimensions http://www.vishay.com/doc?95014					
Part marking information	http://www.vishay.com/doc?95008				
Packaging information	http://www.vishay.com/doc?95032				



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.